NSN 5961-00-337-8785

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-337-8785 **Inclosure Material:** Glass **Overall Length:** 0.405 inches **Overall Height:** 0.405 inches **Overall Width:** 0.437 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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